NSN 5961-01-587-2726

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-587-2726 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **End Application:** 5999-01-583-8311 **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 2.8 regulator voltage and 1.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 20.00 milliamperes voltage regulator diode current **Power Rating Per Characteristic:** 400.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Product Name:** Semiconductor devices, diode, silicon, voltage regulator **Special Features:** No lead surface mounted **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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